

SAMTM Data Sheet SAM-1040-2.5-800fs-x, λ = 1040 nm

Laser wavelength		$\lambda = 1040 \text{ nm}$
High reflection band		λ = 990 1060 nm
Absorbance		A ₀ = 2.5 %
Modulation depth		∆R = 1.5 %
Non-saturable loss		A _{ns} = 1 %
Saturation fluence		Φ_{sat} = 180 µJ/cm ²
Relaxation time constant		τ = 800 fs
Damage threshold		$\Phi = 3 \text{ mJ/cm}^2$
Chip area		4.0 mm x 4.0 mm; other dimensions on request
Chip thickness		450 μm
Protection		the SAM is protected with a dielectric front layer
Mounting optio	x = 0 x = 12.7 g x = 25.4 g	type of mounting as follows: unmounted glued on a gold plated Cu-cylinder with 12.7 mm \emptyset glued on a gold plated Cu-cylinder with 25.4 mm \emptyset
	x = 7340	olleo on a dolo plateo Cu-cylinder Wiln 25.4 mm (2)

x = 25.4 g	glued on a gold plated Cu-cylinder with 25.4 mm $arnothing$
x = 12.7 s	soldered on a gold plated Cu-cylinder with 12.7 mm $arnothing$
x = 25.4 s	soldered on a gold plated Cu-cylinder with 25.4 mm $arnothing$
x = 25.4 w	soldered on a water cooled Cu-cylinder with 25.4 mm $arnothing$
x = FC	mounted on a 1 m monomode fiber cable with FC connector

Low intensity spectral reflectance and dispersion

